Larysa Khomenkova

List of Publications by Year
in descending order

175	1,554	430874 18	477307 29
papers	citations	h-index	g-index

182	182	182	1248
all docs	docs citations	times ranked	citing authors

#	Article	IF	Citations
1	The influence of defect drift in external electric field on green luminescence of ZnO single crystals. Journal of Luminescence, 2003, 102-103, 733-736.	3.1	129
2	The role of oxidation on porous silicon photoluminescence and its excitation. Thin Solid Films, 2001, 381, 88-93.	1.8	48
3	Nature of visible luminescence and its excitation in Siâ€“SiO systems. Journal of Luminescence, 2003, 102-103, 705-711.	3.1	46
4	Ballistic effect in red photoluminescence of Si wires. Physical Review B, 2002, 65, .	3.2	37
5	Nanoscale evidence of erbium clustering in Er-doped silicon-rich silica. Nanoscale Research Letters, 2013, 8, 39.	5.7	34
6	Three approaches to surface substance role investigation in porous silicon photoluminescence and its excitation. Journal of Physics and Chemistry of Solids, 2000, 61, 937-941.	4.0	32
7	Hf-based high-k materials for Si nanocrystal floating gate memories. Nanoscale Research Letters, 2011, 6, 172.	5.7	32
8	Defect-related luminescence of Si/SiO2layers. Journal of Physics Condensed Matter, 2002, 14, 13217-13221.	1.8	30
9	Thermal stability of high-kSi-rich HfO₂layers grown by RF magnetron sputtering. Nanotechnology, 2010, 21, 285707.	2.6	30
10	Complex nature of the red photoluminescence band and peculiarities of its excitation in porous silicon. Applied Surface Science, 2000, 167, 197-204.	6.1	28
11	Hot carriers and excitation of Si/SiOx interface defect photoluminescence in Si nanocrystallites. Physica B: Condensed Matter, 2003, 340-342, 1113-1118.	2.7	27
12	Radiative channel competition in silicon nanocrystallites. Journal of Luminescence, 2005, 115, 117-121.	3.1	27
13	ZnO Nanostructured Microspheres and Elongated Structures Grown by Thermal Treatment of ZnS Powder. Crystal Growth and Design, 2007, 7, 836-839.	3.0	27
14	Effect of the stoichiometry of Si-rich silicon nitride thin films on their photoluminescence and structural properties. Thin Solid Films, 2015, 581, 65-69.	1.8	27
15	Towards an optimum coupling between Er ions and Si-based sensitizers for integrated active photonics. Journal of Applied Physics, 2009, 106, .	2.5	26
16	High-kHf-based layers grown by RF magnetron sputtering. Nanotechnology, 2010, 21, 095704.	2.6	23
17	Microstructure and optical properties of Pr3+-doped hafnium silicate films. Nanoscale Research Letters, 2013, 8, 43.	5.7	20
18	Efficient energy transfer from Si-nanoclusters to Er ions in silica induced by substrate heating during deposition. Journal of Applied Physics, 2010, 108, .	2.5	19

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19	Spectroscopic and structural investigation of undoped and Er3+ doped hafnium silicate layers. Physica B: Condensed Matter, 2014, 453, 100-106.	2.7	18
20	Ag doped silicon nitride nanocomposites for embedded plasmonics. Applied Physics Letters, 2015, 107, .	3.3	18
21	Suboxide-related centre as the source of the intense red luminescence of porous Si. Microelectronic Engineering, 2000, 51-52, 485-493.	2.4	17
22	The influence of crystal imperfections on the shape of exciton emission spectrum in ZnO single crystals. EPJ Applied Physics, 2004, 27, 305-307.	0.7	17
23	Optically active Er3+ ions in SiO2 codoped with Si nanoclusters. Journal of Applied Physics, 2009, 106, 093107.	2.5	16
24	Ge Nanostructures Embedded in ZrO₂ Dielectric Films for Nonvolatile Memory Applications. ECS Transactions, 2015, 66, 203-212.	0.5	16
25	COâ€“PROX reactions on copper Y2O3-ZrO2 catalysts prepared by a single step co-precipitation technique. Applied Catalysis B: Environmental, 2020, 278, 119258.	20.2	16
26	Influence of post annealing treatments on the luminescence of rare earth ions in ZnO:Tb,Eu/Si heterojunction. Applied Surface Science, 2021, 556, 149754.	6.1	16
27	Raman scattering characterization of macro- and nanoporous silicon. Applied Surface Science, 2005, 243, 30-35.	6.1	15
28	Silicon-rich oxynitride hosts for 1.5Î¼m Er3+ emission fabricated by reactive and standard RF magnetron sputtering. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2012, 177, 725-728.	3.5	14
29	Grains, grain boundaries and total ionic conductivity of 10Sc1CeSZ and 8YSZ solid electrolytes affected by crystalline structure and dopant content. Materials Today: Proceedings, 2019, 6, 79-85.	1.8	14
30	Nature of visible luminescence of co-sputtered Siâ€“SiOx systems. Physica B: Condensed Matter, 2003, 340-342, 1119-1123.	2.7	13
31	Hafnia-Based Luminescent Insulator for Phosphor Applications. ECS Transactions, 2012, 45, 119-128.	0.5	13
32	Structural and light emitting properties of silicon-rich silicon nitride films grown by plasma enhanced-chemical vapor deposition. Materials Science in Semiconductor Processing, 2015, 37, 46-50.	4.0	13
33	Effect of Ge Content on the Formation of Ge Nanoclusters in Magnetron-Sputtered GeZrOx-Based Structures. Nanoscale Research Letters, 2017, 12, 196.	5.7	13
34	Emission and structure investigations of Si nano-crystals embedded in amorphous silicon. Journal of Physics: Conference Series, 2007, 61, 1231-1235.	0.4	12
35	Assessment of the main material issues for achieving an Er coupled to silicon nanoclusters infrared amplifier. Physica E: Low-Dimensional Systems and Nanostructures, 2009, 41, 1029-1033.	2.7	12
36	Cathodoluminescence andÂphotoluminescence comparative study of erbium-doped silicon-rich silicon oxide. Journal of Nanophotonics, 2011, 5, 051504.	1.0	12

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37	Atomic scale observation of phase separation and formation of silicon clusters in Hf high-Î² silicates. Journal of Applied Physics, 2012, 111, 103519.	2.5	12
38	Effect of the Si excess on the structure and the optical properties of Nd-doped Si-rich silicon oxide. Journal of Luminescence, 2012, 132, 3118-3121.	3.1	12
39	SiO x /SiN y multilayers for photovoltaic and photonic applications. Nanoscale Research Letters, 2012, 7, 124.	5.7	12
40	Role of paramagnetic defects in light emission processes in Y-doped ZrO2nanopowders. Materials Research Express, 2014, 1, 045011.	1.6	12
41	Thermo-stimulated evolution of crystalline structure and dopant distribution in Cu-doped Y-stabilized ZrO₂nanopowders. Materials Research Express, 2017, 4, 035024.	1.6	12
42	Impurity-Governed Modification of Optical and Structural Properties of ZrO2-Based Composites Doped with Cu and Y. Nanoscale Research Letters, 2017, 12, 157.	5.7	12
43	Photoluminescence, conductivity and structural study of terbium doped ZnO films grown on different substrates. Materials Science in Semiconductor Processing, 2019, 94, 51-56.	4.0	12
44	Photoluminescence engineering in polycrystalline ZnO and ZnO-based compounds. AIMS Materials Science, 2016, 3, 508-524.	1.4	12
45	Two ways of porous Si photoluminescence excitation. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 1998, 51, 162-165.	3.5	11
46	USXES AND OPTICAL PHENOMENA IN Si LOW-DIMENSIONAL STRUCTURES DEPENDENT ON MORPHOLOGY AND SILICON OXIDE COMPOSITION ON Si SURFACE. Surface Review and Letters, 2002, 09, 1047-1052.	1.1	11
47	Luminescence and EPR studies of defects in Si-SiO2films. EPJ Applied Physics, 2004, 27, 285-287.	0.7	11
48	The effect of oxidation on the efficiency and spectrum of photoluminescence of porous silicon. Semiconductors, 2006, 40, 598-604.	0.5	11
49	Correlation between the photoluminescence and different types of Si nano-clusters in amorphous silicon. Journal of Non-Crystalline Solids, 2008, 354, 2186-2189.	3.1	11
50	The nature of emission of porous silicon produced by chemical etching. Semiconductors, 2010, 44, 79-83.	0.5	11
51	Guided photoluminescence study of Nd-doped silicon rich silicon oxide and silicon rich silicon nitride waveguides. Journal of Applied Physics, 2013, 114, .	2.5	11
52	Redistribution of Tb and Eu ions in ZnO films grown on different substrates under thermal annealing and its impact on Tb-Eu energy transfer. Applied Surface Science, 2020, 528, 146913.	6.1	11
53	Photoluminescence and EPR studies of porous silicon. Journal of Luminescence, 1997, 72-74, 400-402.	3.1	10
54	Further improvements in Er3+coupled to Si nanoclusters rib waveguides. , 2008, , .		10

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55	Si-rich Al2O3 films grown by RF magnetron sputtering: structural and photoluminescence properties versus annealing treatment. Nanoscale Research Letters, 2013, 8, 273.	5.7	10
56	The influence of annealing on structural and photoluminescence properties of silicon-rich Al2O3 films prepared by co-sputtering. Physica E: Low-Dimensional Systems and Nanostructures, 2013, 51, 115-119.	2.7	10
57	Structural and Luminescent Properties of (Y,Cu)-Codoped Zirconia Nanopowders. ECS Journal of Solid State Science and Technology, 2015, 4, N103-N110.	1.8	10
58	Annealing impact on emission and phase varying of Nd-doped Si-rich-HfO2 films prepared by RF magnetron sputtering. Journal of Materials Science: Materials in Electronics, 2020, 31, 4587-4594.	2.2	10
59	Two sources of excitation of photoluminescence of porous silicon. Semiconductors, 1997, 31, 773-776.	0.5	9
60	Mechanism of photoexcitation of oxide-related emission bands in Siâ€“SiO2 systems. Materials Science and Engineering C, 2003, 23, 691-696.	7.3	9
61	Depth redistribution of components of SiOx layers prepared by magnetron sputtering in the process of their decomposition. Thin Solid Films, 2007, 515, 6749-6753.	1.8	9
62	The structure of Siâ€“SiO2 layers with high excess Si content prepared by magnetron sputtering. Thin Solid Films, 2009, 517, 5468-5473.	1.8	9
63	Hafnium silicate dielectrics fabricated by RF magnetron sputtering. Journal of Non-Crystalline Solids, 2011, 357, 1860-1865.	3.1	9
64	Atomic scale microstructures of high-k HfSiO thin films fabricated by magnetron sputtering. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2012, 177, 717-720.	3.5	9
65	Nanostructured Y-doped ZrO2 powder: peculiarities of light emission under electron beam excitation. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 1417-1422.	0.8	9
66	Optical properties of Zr and ZrO2. Applied Surface Science, 2017, 421, 744-747.	6.1	9
67	Origin of Pr³⁺ luminescence in hafnium silicate films: combined atom probe tomography and TEM investigations. Nano Futures, 2018, 2, 035005.	2.2	9
68	Investigation of undoped and Tb-doped ZnO films on Al2O3 substrate by infrared reflection method. Thin Solid Films, 2019, 673, 136-140.	1.8	9
69	Transformations in the photoluminescent, electrical and structural properties of Tb3+ and Eu3+ co-doped ZnO films under high-temperature annealing. Journal of Luminescence, 2020, 217, 116739.	3.1	9
70	Investigation of aging process of Siâ€“SiOx structures with silicon quantum dots. Journal of Applied Physics, 2005, 98, 113515.	2.5	8
71	Undoped and Nd³⁺ doped Si-based single layers and superlattices for photonic applications. Physica Status Solidi (A) Applications and Materials Science, 2013, 210, 1532-1543.	1.8	8
72	Optical, structural and electrical characterizations of stacked Hf-based and silicon nitride dielectrics. Thin Solid Films, 2016, 617, 143-149.	1.8	8

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73	Modification of Light Emission in Si-Rich Silicon Nitride Films Versus Stoichiometry and Excitation Light Energy. Journal of Electronic Materials, 2018, 47, 3927-3933.	2.2	8
74	Effect of adsorption and desorption processes on photoluminescence excitation spectra of porous silicon. Applied Surface Science, 2000, 166, 349-353.	6.1	7
75	Long lifetime and efficient emission from Er3+ ions coupled to Si nanoclusters in Si-rich SiO2 layers. Journal of Luminescence, 2009, 129, 1519-1523.	3.1	7
76	Thermal Treatments and Photoluminescence Properties of ZnO and ZnO:Yb Films Grown by Magnetron Sputtering. Physica Status Solidi (A) Applications and Materials Science, 2019, 216, 1800203.	1.8	7
77	Optical and structural properties of Mn-doped magnesium titanates fabricated with excess MgO. Materials Today Communications, 2021, 27, 102373.	1.9	7
78	The investigation of 10Sc1CeSZ structure transformation and ionic conductivity. Materials Today: Proceedings, 2022, 50, 487-491.	1.8	7
79	Photoluminescence and structure investigations of Si nano-crystals in amorphous silicon matrix. Journal of Non-Crystalline Solids, 2006, 352, 1188-1191.	3.1	6
80	Towards an enhanced coupling between the Er ions and Si nanoclusters. Physica E: Low-Dimensional Systems and Nanostructures, 2009, 41, 1048-1051.	2.7	6
81	Effect of Li+ co-doping on structural and luminescence properties of Mn4+ activated magnesium titanate films. Journal of Materials Science: Materials in Electronics, 2018, 29, 15613-15620.	2.2	6
82	The Effect of High Temperature Annealing on the Photoluminescence of ZnMgO Alloys. Physica Status Solidi (A) Applications and Materials Science, 2018, 215, 1800250.	1.8	6
83	Light emission and structure of Nd-doped Si-rich-HfO2 films prepared by magnetron sputtering in different atmospheres. Materials Chemistry and Physics, 2019, 229, 263-268.	4.0	6
84	The peculiarities of structural and optical properties of HfO2-based films co-doped with silicon and erbium. Applied Surface Science, 2019, 471, 521-527.	6.1	6
85	Light Emission in Nd Doped Si-Rich HfO2 Films Prepared by Magnetron Sputtering. Journal of Electronic Materials, 2020, 49, 3441-3449.	2.2	6
86	Optical, structural and electrical characterization of pure ZnO films grown on p-type Si substrates by radiofrequency magnetron sputtering in different atmospheres. Semiconductor Science and Technology, 2020, 35, 095034.	2.0	6
87	Investigation of lattice defects by means of their drift under electric field. Physica B: Condensed Matter, 2001, 308-310, 967-970.	2.7	5
88	Some Peculiarities of Impurity Diffusion in CdS Crystals. Physica Status Solidi (B): Basic Research, 2002, 229, 269-273.	1.5	5
89	Ballistic effect and photoluminescence excitation in porous silicon. Surface Science, 2003, 532-535, 1204-1208.	1.9	5
90	Structural and light emission properties of silicon-based nanostructures with high excess silicon content. Physica E: Low-Dimensional Systems and Nanostructures, 2009, 41, 1015-1018.	2.7	5

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91	Structural and optical characteristics of Er-doped SRSO layers deposited by the confocal sputtering technique. Physica E: Low-Dimensional Systems and Nanostructures, 2009, 41, 1067-1070.	2.7	5
92	Rare-earth (Er, Nd)-doped Si nanostructures for integrated photonics. Physica E: Low-Dimensional Systems and Nanostructures, 2009, 41, 1034-1039.	2.7	5
93	Structural, electrical and luminescent properties of ZnO:Li films fabricated by screenâ€printing method on sapphire substrate. Physica Status Solidi C: Current Topics in Solid State Physics, 2015, 12, 1144-1147.	0.8	5
94	Light emitting mechanisms in Siâ€rich SiN‹sub›x‹/sub› films with different silicon nitride stoichiometry. Physica Status Solidi (B): Basic Research, 2017, 254, 1600670.	1.5	5
95	Emitting modification in Si-rich-SiNx films versus silicon nitride compositions. MRS Communications, 2017, 7, 280-285.	1.8	5
96	Influence of annealing on luminescence and energy transfer in ZnO multilayer structure co-doped with Tb and Eu. Thin Solid Films, 2019, 692, 137634.	1.8	5
97	Phase transformation and light emission in Er-doped Si-rich HfO2 films prepared by magnetron sputtering. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2019, 37, 031503.	2.1	5
98	Optical and Electrical Properties of Tbâ€“ZnO/SiO2 Structure in the Infrared Spectral Interval. Ukrainian Journal of Physics, 2019, 64, 434.	0.2	5
99	Silicon nanocrystals embedded in oxide films grown by magnetron sputtering. AIMS Materials Science, 2016, 3, 538-561.	1.4	5
100	The interrelation of surface relief of porous silicon with specific features of Raman spectra. Semiconductors, 2002, 36, 558-563.	0.5	4
101	Magnetic field effect on the visible photoluminescence of porous silicon. Physica Status Solidi C: Current Topics in Solid State Physics, 2005, 2, 3314-3318.	0.8	4
102	Size Dependent Photoluminescence of Si Nano-Crystals Embedded in Amorphous Silicon. Solid State Phenomena, 2008, 131-133, 71-76.	0.3	4
103	Growth peculiarities of silicon nanoparticles in an oxide matrix prepared by magnetron sputtering. Physica Status Solidi C: Current Topics in Solid State Physics, 2007, 4, 3061-3065.	0.8	4
104	Structural and luminescent characteristics of macro porous silicon. Journal of Materials Science: Materials in Electronics, 2009, 20, 226-229.	2.2	4
105	Ge-Doped Hafnia-Based Dielectrics for Non-Volatile Memory Applications. ECS Transactions, 2012, 45, 331-344.	0.5	4
106	Structure and light emission of Si-rich Al2O3 and Si-rich-SiO2 nanocomposites. Microelectronic Engineering, 2014, 125, 62-67.	2.4	4
107	Effect of Cu- and Y-Codoping on Structural and Luminescent Properties of Zirconia Based Nanopowders. ECS Transactions, 2015, 66, 313-319.	0.5	4
108	Optical and structural characterization of Ge clusters embedded in ZrO2. Applied Surface Science, 2017, 421, 283-288.	6.1	4

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109	Peculiarities of Thermally Activated Migration of Subvalent Impurities in Cu-Doped Y-Stabilized ZrO2 Nanopowders Produced From Zr Oxychlorides. Frontiers in Materials, 2018, 5, .	2.4	4
110	Thermally induced evolution of optical and structural properties of Er2O3 films grown on Si substrates by thermal atomic layer deposition. Materials Letters, 2020, 263, 127216.	2.6	4
111	The role of excess MgO in the intensity increase of red emission of Mn4+-activated Mg2TiO4 phosphors. Journal of Materials Science: Materials in Electronics, 2020, 31, 7555-7564.	2.2	4
112	Effect of plasmonâ€“phonon interaction on the infrared reflection spectra of MgxZn1-xO/Al2O3 structures. Journal of Materials Science: Materials in Electronics, 2020, 31, 7539-7546.	2.2	4
113	Raman scattering, emission and crystalline phase evolutions in Nd-doped Si-rich HfO2:N films. Journal of Materials Science: Materials in Electronics, 2021, 32, 17473-17481.	2.2	4
114	Stability of Emission Properties of Silicon Nanostructures. Solid State Phenomena, 2005, 108-109, 59-64.	0.3	3
115	Structure and Optical Properties of Magnetron Sputtered SiO_x Layers with Silicon Nanoparticles. Defect and Diffusion Forum, 2008, 272, 87-98.	0.4	3
116	HfO2-based Thin Films Deposited by RF Magnetron Sputtering. Materials Research Society Symposia Proceedings, 2009, 1160, 1.	0.1	3
117	The peculiarities of Si/SiO2 interfaces in the Siâ€“SiO2 systems with Si nanocrystals. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2010, 174, 97-101.	3.5	3
118	Light-Emitting and Structural Properties of Si-rich HfO2 Thin Films Fabricated by RF Magnetron Sputtering. Materials Research Society Symposia Proceedings, 2013, 1617, 85-91.	0.1	3
119	Analysis of PL spectrum shape of Si-based materials as a tool for determination of Si crystallites×3 distribution. Physica B: Condensed Matter, 2014, 453, 19-25.	2.7	3
120	Effect of Rare-Earth Doping on Structural and Luminescent Properties of Screen-Printed ZnO Films. ECS Transactions, 2015, 66, 321-332.	0.5	3
121	Spectroscopic characterization of phase transformation in Ge-rich Al2O3 films grown by magnetron co-sputtering. Materials Letters, 2020, 277, 128306.	2.6	3
122	Thermally Stimulated Evolution of Optical and Structural Properties of Germanium-Doped Alumina Films. ECS Transactions, 2020, 97, 81-90.	0.5	3
123	Formation of Si/SiOx interface and its influence on photoluminescence of Si nano-crystallites. Microelectronics Journal, 2003, 34, 759-761.	2.0	2
124	Photoluminescence and its excitation mechanisms in Si wires and dots. Physica Status Solidi A, 2003, 197, 382-387.	1.7	2
125	Defect and nano-crystallite photoluminescence in Si-SiOx systems. Physica Status Solidi C: Current Topics in Solid State Physics, 2005, 2, 2990-2993.	0.8	2
126	Enhanced fraction of coupled Er in silicon-rich silicon oxide layers grown by magnetron co-sputtering. Journal of Luminescence, 2009, 129, 1886-1889.	3.1	2

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127	Silicon Nanoclusters Embedded into Oxide Host for Non-Volatile Memory Applications. ECS Transactions, 2011, 35, 37-45.	0.5	2
128	Comparative Investigation of Structural and Optical Properties of Si-Rich Oxide Films Fabricated by Magnetron Sputtering. Advanced Materials Research, 0, 854, 117-124.	0.3	2
129	Interrelation between Light Emitting and Structural Properties of Si Nanoclusters Embedded in SiO2 and Al2O3 Hosts. Materials Research Society Symposia Proceedings, 2013, 1617, 75-80.	0.1	2
130	Effect of Li-doping on Photoluminescence of Screen-printed Zinc Oxide Films. Materials Research Society Symposia Proceedings, 2015, 1766, 167-177.	0.1	2
131	Emission Dependent on composition of Si-rich-SiNX Films obtained by PECVD. IOP Conference Series: Materials Science and Engineering, 2017, 169, 012021.	0.6	2
132	Light emitting mechanisms dependent on stoichiometry of Si-rich-SiNx films grown by PECVD. Journal of Materials Science: Materials in Electronics, 2017, 28, 6977-6981.	2.2	2
133	The peculiarities of light absorption and light emission in Cu-doped Y-stabilized ZrO2 nanopowders. Applied Nanoscience (Switzerland), 2019, 9, 965-973.	3.1	2
134	Correlation of luminescence measurements to the structural characterization of Pr3+-doped HfSiOx. Journal of Luminescence, 2021, 235, 118004.	3.1	2
135	Effect of Cooling Rate on Dopant Spatial Localization and Phase Transformation in Cuâ€Doped Yâ€Stabilized ZrO ₂ Nanopowders. Physica Status Solidi C: Current Topics in Solid State Physics, 2017, 14, 1700183.	0.8	2
136	Chemical composition and light emission properties of Si-rich-SiOx layers prepared by magnetron sputtering. Semiconductor Physics, Quantum Electronics and Optoelectronics, 2008, 10, 21-25.	1.0	2
137	Size- and position-controlled Ge nanocrystals separated by high-k dielectrics. MRS Bulletin, 2022, 47, 773-782.	3.5	2
138	Complex studies of porous silicon aging phenomena. , 0, , .		1
139	Oxidation process effects on porous silicon photoluminescence. , 0, , .		1
140	Effect of Various Treatments on Light Emission Properties of Si-Rich-SiO_x Structures. Solid State Phenomena, 2007, 131-133, 65-70.	0.3	1
141	xmlns:xocs="http://www.elsevier.com/xml/xocs/dtd" xmlns:xs="http://www.w3.org/2001/XMLSchema" xmlns:xsi="http://www.w3.org/2001/XMLSchema-instance" xmlns="http://www.elsevier.com/xml/ja/dtd" xmlns:ja="http://www.elsevier.com/xml/ja/dtd" xmlns:mml="http://www.w3.org/1998/Math/MathML" xmlns:tb="http://www.elsevier.com/xml/common/table/dtd"	1.2	1
142	Optical and structural properties of SiO 2 co-doped with Si-nc and Er3+ions. , 2010, , .		1
143	Effect of annealing treatment on Nd-SiO x thin film properties. Proceedings of SPIE, 2012, , .	0.8	1
144	Charge Trapping in Hafnium Silicate Films with Modulated Composition and Enhanced Permittivity. Advanced Materials Research, 2013, 854, 125-133.	0.3	1

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145	Phonon-Polariton Excitations in MgZnO/6H-SiC Structures. Ukrainian Journal of Physics, 2020, 65, 162.	0.2	1
146	The nature of photoluminescence excitation bands in porous silicon. , 0, , .		0
147	<title>Role of surface substances in excitation of porous silicon photoluminescence</title>. , 1999, , .		0
148	Nature of the red photoluminescence in porous silicon. , 0, , .		0
149	The influence of defect diffusion under electric field on optical and luminescent characteristics of cadmium sulphide. , 0, , .		0
150	Temperature effect on photoluminescence excitation process of porous silicon. , 0, , .		0
151	Peculiarities of Raman spectra from porous silicon. , 0, , .		0
152	Si Wire Light Emission Changes During Si/SiOx Interface Formation. Materials Research Society Symposia Proceedings, 2004, 808, 215.	0.1	0
153	Er³⁺ coupled to Si nanoclusters rib waveguides. , 2008, , .		0
154	Stable HfO2 based Layers Fabricated by RF Magnetron Sputtering. ECS Transactions, 2009, 25, 153-162.	0.5	0
155	Study of the electroluminescence at 1.5 μm of SiO<inf>x</inf> :Er layers made by reactive magnetron sputtering. , 2009, , .		0
156	Study of the layer-substrate interface in nc-Si-SiO2-p-Si structures with silicon quantum dots by the method of temperature dependences of photovoltage. Semiconductors, 2010, 44, 1187-1191.	0.5	0
157	Structure and Optical Properties of Magnetron-Sputtered SiO_x Layers with Silicon Nanoparticles. Defect and Diffusion Forum, 0, 303-304, 7-19.	0.4	0
158	Memory effect in nanostructured Si-rich hafnia films. Materials Research Society Symposia Proceedings, 2013, 1617, 69-74.	0.1	0
159	Preface of the "Symposium on theory, modeling, investigation and simulation of low-dimensional semiconductor systems". , 2014, , .		0
160	Analysis of carrier injection in Si nanoparticle-SiOx film based MOS devices. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 206-210.	0.8	0
161	Low-Dimensional Semiconductor Structures â€“ A part of the XXII International Material Research Congress (IMRC 2013). Physica B: Condensed Matter, 2014, 453, iii.	2.7	0
162	High-k MNOS-Like Stacked Dielectrics for Non-Volatile Memory Application. Journal of Nano Research, 2016, 39, 121-133.	0.8	0

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163	Whether Ge-Rich ZrO2 and Ge-Rich HfO2 Materials Have Similar Reaction on Annealing Treatment?. ECS Transactions, 2020, 97, 49-60.	0.5	0
164	New Paramagnetic Center in Cu-Doped Y-Stabilized ZrO2. ECS Journal of Solid State Science and Technology, 2020, 9, 033002.	1.8	0
165	Evolution of Morphology, Structure and Emission in Si-rich HfO2:Nd films with Annealing Times. Journal of Physics: Conference Series, 2021, 1723, 012044.	0.4	0
166	Annealing Impact on the Evolution of Crystalline Phases and Emission in Si-Rich HfO2:Nd Films Obtained By Magnetron Sputtering. ECS Meeting Abstracts, 2021, MA2021-01, 848-848.	0.0	0
167	Structure and Emission Evolution in Si-Rich HfO2:Pr Films Versus Annealing Temperature. ECS Meeting Abstracts, 2021, MA2021-01, 849-849.	0.0	0
168	Several Ways of Excitation and Degradation Processes of Porous Silicon Photoluminescence. , 1998, , 305-309.		0
169	Solid State Nanocomposites and Hybrid Systems. , 2018, , 2-26.		0
170	Multifunctional Zirconia-based Nanocomposites. , 2018, , 28-57.		0
171	Solid State Composites and Multilayers Produced by Magnetron Sputtering. , 2018, , 152-185.		0
172	Whether Ge-Rich ZrO2 and Ge-Rich HfO2 Materials Have Similar Reaction on Annealing Treatment?. ECS Meeting Abstracts, 2020, MA2020-01, 1027-1027.	0.0	0
173	Thermally Stimulated Evolution of Optical and Structural Properties of Germanium-Doped Alumina Films. ECS Meeting Abstracts, 2020, MA2020-01, 1091-1091.	0.0	0
174	(Invited) Luminescence of Rare Earth Doped Si Based Nanofilms for LED and Photovoltaic Applications. ECS Meeting Abstracts, 2020, MA2020-01, 1064-1064.	0.0	0
175	(Invited) Rare Earth Doped Layers Fabricated By Atomic Layer Deposition. ECS Meeting Abstracts, 2020, MA2020-01, 1066-1066.	0.0	0